PATENT



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant

Venkatapathi R. Nallapa

Application No.

10/658,124

.1.

Filed

September 9, 2003

For

EEPROM EMULATION IN FLASH MEMORY

Art Unit

: 2818

Docket No.

: 130209.511

Date

: December 18, 2003

Mail Stop Missing Parts Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents:

In accordance with 37 C.F.R. §§ 1.56 and 1.97 through 1.98, applicant wishes to make known to the U.S. Patent and Trademark Office the references set forth on the attached form PTO-1449 (copies of the cited references are enclosed). As to any reference supplied, applicant does not admit that it is "prior art" under 35 U.S.C. §§ 102 or 103, and specifically reserves the right to traverse or antedate any such reference, as by a showing under 37 C.F.R. § 1.131 or other method. Although the aforesaid references are made known to the Patent and Trademark Office in compliance with applicant's duty to disclose all information he is aware of which is believed relevant to the examination of the above-identified application, applicant believes that his invention is patentable.

Please acknowledge receipt of this Information Disclosure Statement and kindly make the cited references of record in the above-identified application.

Applicant believes this Information Disclosure Statement has been timely filed, however, the Director is authorized to charge any fee due by way of this Information Disclosure Statement to our Deposit Account No. 19-1090.

Respectfully submitted,

Seed Intellectual Property Law Group PLLC

Frank Abramonte

Registration No. 38,066

Enclosures:

Form PTO-1449 Cited References (4)

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Sheet 1 of 1

FORM PTO-1449 (REV.7-80)		PATE	DEPARTMENT OF NT AND TRADER	130209.511 10/6 APPLICANT			PLICATION NO. 0/658,124				
INFORMATION DISCLOSURE STATEMENT (Use several sheets if necessary) DEC 1 8 2003					Venkatapathi R. Nallapa FILING DATE GROUP ART UNIT September 9, 2003 2818			=			
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OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)											
	"EEPROM Replacement with Flash Memory – Intel Application Note AP-685," Intel										
			Corporation, Denver, CO, December 1998, pp 1-20.								
	AN		Hazen, P., "Using Intel's Boot Block Flash Memory Parameter Blocks to Replace Eeprom - Intel Application Note AP-604," Intel Corporation, Denver, CO, November 1995, pp 1-6.								
	AO		"Am29F200B Data Sheet," Advanced Micro Devices (AMD), Publication # 21526, Rev: C								
		ı	Amendment/+2, Sunnyvale, CA, November 1999, pp 1-39.								
	АР	ſ	STMicroelectonics, "Flash+, Exit the Emulation Compromise," ST Challenge, 4th Edition,								
1997, retrieved from http://us.st.com/stonline/press/magazine/challeng/4thedit/chal5.h EXAMINER DATE CONSIDERED										tm.	
* EXAMINER: Initial if reference considered, whether or not criteria is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).											
434926 Date: 12/18/03											